



DESCRIPTION:

The CENTRAL SEMICONDUCTOR CSHD3-40, silicon schottky rectifier is a high quality, well constructed, highly reliable component designed for use in all types of commercial, industrial, entertainment, computer and automotive applications.

MARKING CODE: FULL PART NUMBER

MAXIMUM RATINGS: (T_C=25°C unless otherwise noted)

	SYMBOL		UNITS
Peak Repetitive Reverse Voltage	V _{RRM}	40	V
Average Rectified Forward Current (T _C =120°C)	lO	3.0	А
Peak Forward Surge Current (tp=10ms)	IFSM	75	А
Peak Repetitive Reverse Surge Current (tp=2µs)	IRRM	1.0	А
Critical Rate of Rise of Reverse Voltage	dv/dt	10,000	V/µs
Operating and Storage			
Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	Θ^{JC}	5.5	°C/W

ELECTRICAL CHARACTERISTICS: (T_C=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
۱ _R	V _R =40V		100	μΑ
I _R	V _R =40V, T _C =125°C		10	mA
V _F	I _F =3.0A		0.65	V
V _F	I _F =3.0A, T _C =125°C		0.60	V

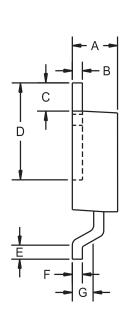
R6 (26-September 2002)

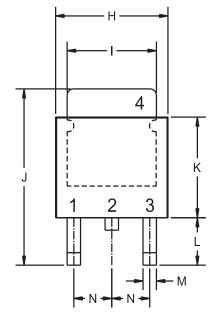


CSHD3-40

SCHOTTKY RECTIFIER SINGLE, 3.0 AMPS, 40 VOLTS

DPAK RECTIFIER CASE - MECHANICAL OUTLINE





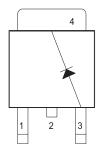
R1

LEAD CODE:

1) NO CONNECTION 2) CATHODE 3) ANODE 4) CATHODE

PIN 2 IS COMMON TO THE TAB (4).

MARKING CODE: FULL PART NUMBER



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
А	0.093	0.108	2.35	2.75			
В	0.016	0.024	0.40	0.60			
С	0.063		1.60				
D	0.203	0.219	5.15	5.55			
E	0.012	0.028	0.30	0.70			
F	0.020		0.50				
G	0.035	0.051	0.90	1.30			
Н	0.252	0.268	6.40	6.80			
	0.197	0.213	5.00	5.40			
J	-	0.394	-	10.00			
K	0.209	0.224	5.30	5.70			
L	0.090	0.106	2.30	2.70			
М	0.016	0.031	0.40	0.80			
N	0.091		2.30				

DPAK RECTIFIER (REV: R1)

R6 (26-September 2002)